DESCRIPTION

The SPN3402W is the N-Channel logic enhancement mode power field effect transistors are produced using high cell density, DMOS trench technology.

This high density process is especially tailored to minimize on-state resistance.

These devices are particularly suited for low voltage application such as cellular phone and notebook computer power management and other battery powered circuits, and low in-line power loss are needed in a very small outline surface mount package.

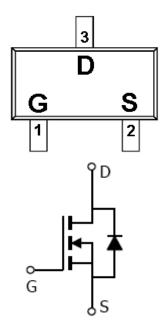
APPLICATIONS

- Power Management in Note book
- Portable Equipment
- Battery Powered System
- DC/DC Converter
- Load Switch
- DSC
- LCD Display inverter

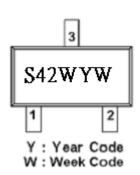
FEATURES

- 30V/2.8A,RDS(ON)= $58m\Omega$ @VGS=10V
- 30V/2.3A,RDS(ON)= $65m\Omega$ @VGS=4.5V
- 30V/1.5A,RDS(ON)= $105m\Omega$ @VGS=2.5V
- ◆ Super high density cell design for extremely low RDS(ON)
- Exceptional on-resistance and maximum DC current capability
- ♦ SOT-23 package design

PIN CONFIGURATION (SOT-23)



PART MARKING



PIN DESCRIPTION						
Pin	Symbol	Description				
1	G	Gate				
2	S	Source				
3	D	Drain				

ORDERING INFORMATION

Part Number	Package	Part Marking
SPN3402WS23RGB	SOT-23	S42W

Week Code : $A \sim Z(1 \sim 26)$; $a \sim z(27 \sim 52)$

※ SPN3402WS23RGB: Tape Reel; Pb − Free; Halogen − Free

ABSOULTE MAXIMUM RATINGS

(Ta=25°C Unless otherwise noted)

Parameter		Symbol	Typical	Unit	
Drain-Source Voltage		Vdss	30	V	
Gate –Source Voltage		VGSS	±12	V	
Continuous Drain Current(TJ=150°C)	Ta=25°C	- Id	4.0	A	
Continuous Brain Current(17-130 C)	Ta=70°C		2.8	71	
Pulsed Drain Current		Ірм	10	A	
Continuous Source Current(Diode Conduction)		Is	1.25	A	
Davis Discipation	Ta=25°C	PD	1.25	***	
Power Dissipation	Ta=70°C		0.8	W	
Operating Junction Temperature		τT	150	°C	
Storage Temperature Range		Tstg	-55/150	°C	
Thermal Resistance-Junction to Ambient		RθJA	100	°C/W	

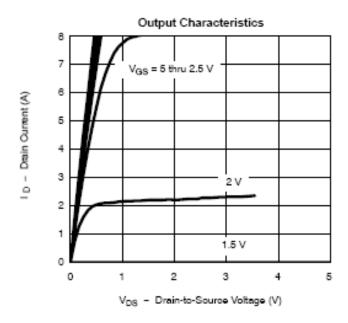


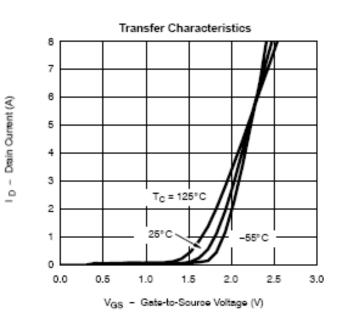
ELECTRICAL CHARACTERISTICS

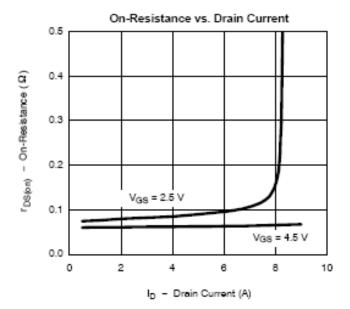
(TA=25°C Unless otherwise noted)

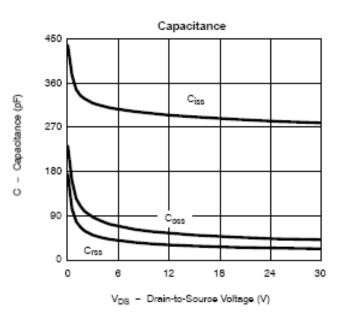
Parameter	Symbol	Conditions	Min.	Тур	Max.	Unit
Static						
Drain-Source Breakdown Voltage	V(BR)DSS	VGS=0V,ID=250uA	30			V
Gate Threshold Voltage	VGS(th)	VDS=VGS,ID=250uA	0.5		1.6] v
Gate Leakage Current	Igss	VDS=0V,VGS=±12V			±100	nA
		VDS=24V,VGS=0.0V			1	uA
Zero Gate Voltage Drain Current	Idss	V _{DS} =24V,V _{GS} =0.0V T _J =55°C			10	
On-State Drain Current	T	$V_{DS} \ge 4.5V, V_{GS} = 10V$	6			A
	ID(on)	$V_{DS} \ge 4.5V, V_{GS} = 4.5V$	4			
Drain-Source On-Resistance	RDS(on)	VGS = 10V,ID=2.8A		0.048	0.058	Ω
		VGS =4.5V,ID=2.3A		0.053	0.065	
		VGS =2.5V,ID=1.5A		0.080	0.105	
Forward Transconductance	gfs	Vds=4.5V,Id=2.8A		4.6		S
Diode Forward Voltage	Vsd	Is=1.25A,VGS=0V		0.82	1.2	V
Dynamic						
Total Gate Charge	Qg			4.2	6	nC
Gate-Source Charge	Qgs	VDS=15,VGS=4.5V ID=2.0A		0.6		
Gate-Drain Charge	Qgd	-ID-2.0A		1.5		
Input Capacitance	Ciss			350		pF
Output Capacitance	Coss	$V_{DS}=15,V_{GS}=0V$ f=1MHz		55		
Reverse Transfer Capacitance	Crss	-I -IMITZ		41		
Turn-On Time	td(on)			2.5		nS
	tr	$V_{DD}=15,RL=10\Omega$		2.5		
Turn-Off Time	td(off)	$V_{GEN=10V,RG=3\Omega}$		20		
	tf	1		4		

TYPICAL CHARACTERISTICS

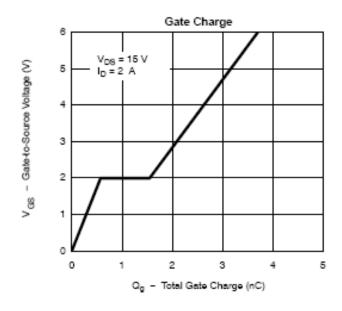


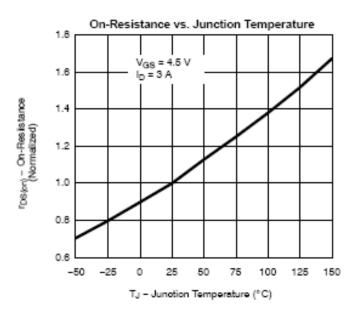


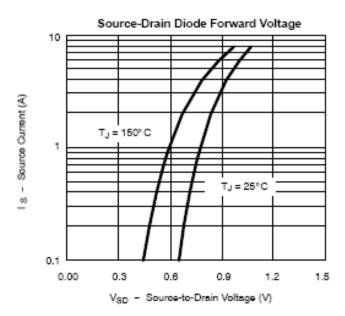


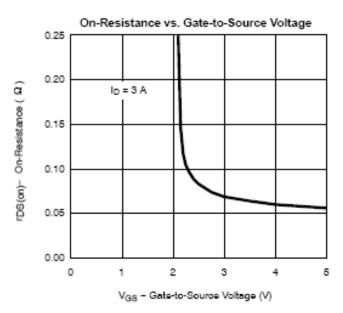


TYPICAL CHARACTERISTICS



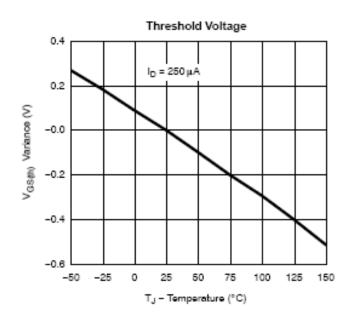


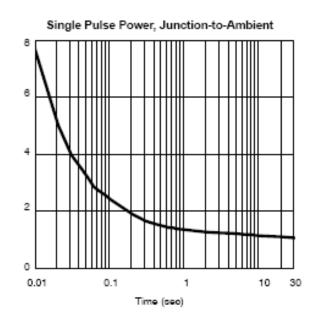


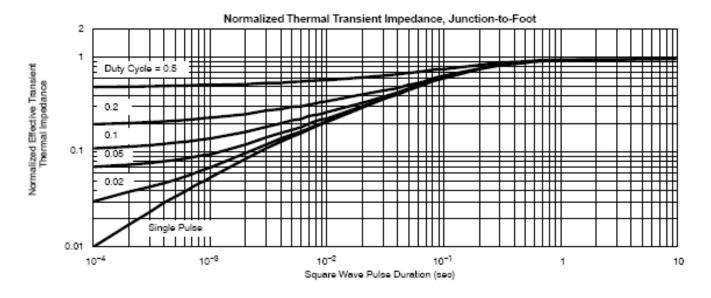


Power (W)

TYPICAL CHARACTERISTICS







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SYNC Power Corporation
7F-2, No.3-1, Park Street
NanKang District (NKSP), Taipei, Taiwan, 115, R.O.C
Phone: 886-2-2655-8178
Fax: 886-2-2655-8468

Fax: 886-2-2655-8468 © http://www.syncpower.com